

# MOS OPERATION.

3 JANUARY 2006

## MOS TRANSISTOR.

### ☛ Features :

- ◇ Technology is very scalable.
- ◇ Smallest sized circuits can be fabricated.
- ◇ Digital circuits have simplest realizations in CMOS.
- ◇ MOS transistors act as an ideal switch.

### MOS transistor operation.

- ☛  $V_{GB}$  is negative , holes will be attracted from bulk ACCUMULATION REGION
- ☛ If  $V_{GB} > 0$  holes will be repelled and depletion region will be formed.
- ☛ If  $V_{GB}$  again increased electrons will be attracted.
- ☛ If  $V_{GB} > V_{th}$  then inversion layer will be formed CHANNEL FORMATION.

### ☛ assumptions :

- ◇  $V_{GB} < V_{th}, Q_I = 0$
- ◇  $V_{GB} > V_{th}, Q_I = -C_{ox}(V_{gb} - V_{th})$
- ◇  $C'_{ox} = \frac{\epsilon_{ox}}{t_{ox}}$
- ◇  $C_{ox} = C'_{ox}WL$

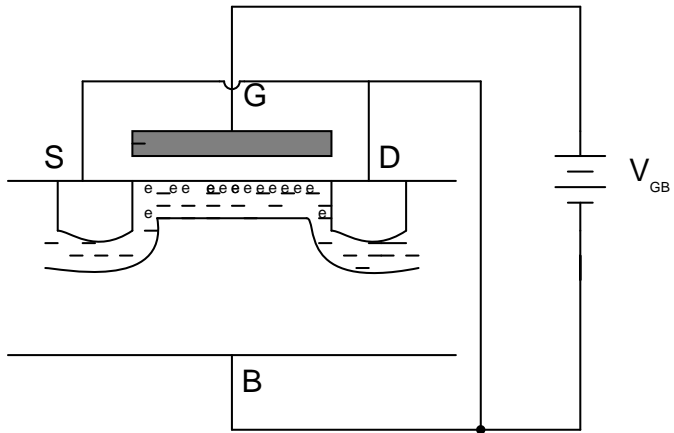


Figure 1: MOS operation